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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)			APPLICANT				
			Louis L. Hsu et al.				
			FILING DATE	GROUP ART UNIT			
			August 19, 2003				
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
							YES NO
OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
<i>MW</i>		Hang Hu, et al., <u>A High Performance MIM Capacitor Using HfO₂ Dielectrics</u> , IEEE Electron Device Letters, Vol. 23, No. 9, September 2002, pp. 514-516.					
EXAMINER <i>MWilczewski</i>			DATE CONSIDERED <i>6/2005</i>				
* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							

(Form PTO-1449 [6-4])